NSN 5962-01-341-2450



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View Online at https://aerobasegroup.com/nsn/5962-01-341-2450	
Overall Height:	
0.400 inches	
Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
1.0 watts	
Operating Tempurature Range:	
-55.0/+110.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Dynamic and monolithic and w/clock and w/buffered output	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
N-type metal oxide-semiconductor logic	
Input Circuit Pattern:	
13 input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
Current Rating Per Characteristic:	
90.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Product Name:	

Dynamic random access memory

Voltage Rating And Type Per Characteristic:

-1.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

Err-060 and err-060

Time Rating Per Chacteristic:

60.00 nanoseconds access and 120.00 nanoseconds access

Memory Device Type:

Ram

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

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16 printed circuit

Specification Data:

81349-mil-m-38510/246 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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